GM1117A

1A Low Dropout Positive Adjustable or Fixed-Mode Regulator

Description

The GM1117A is a low dropout at positive adjustable or fixed-mode regulator with minimum of 1A output current capability. The product is specifically designed to provide well-regulated supply for low voltage IC applications such as high-speed bus termination and low current 3.3V logic supply. GM1117A is also well suited for other applications such as VGA cards. GM1117A is guaranteed to have lower than 1.4V dropout at full load current making it ideal to provide well-regulated outputs of 1.25 to 5.0 with 6.4V to 12V input supply.

Features

1.4Vmaximum dropout full load current

&Fast transient response

&Output current limiting

&Built-in thermal shutdown

&Good noise rejection

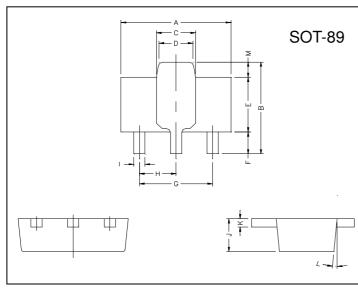
&3-Terminal Adjustable or Fixed 1.5V,1.8V,2.5V,3.3V,5.0V

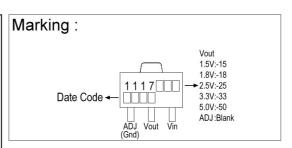
Applications

PC peripheral

&Communication

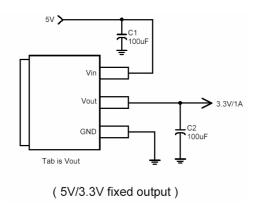
Package Dimensions

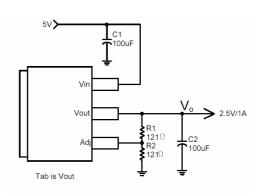




REF.	Millimeter		REF.	Millimeter		
	Min.	Max.	nLi.	Min.	Max.	
Α	4.4	4.6	G	3.00 REF.		
В	4.05	4.25	Н	1.50 REF.		
С	1.50	1.70	1	0.40	0.52	
D	1.30	1.50	J	1.40	1.60	
Е	2.40	2.60	K	0.35	0.41	
F	0.89	1.20	L	5° TYP.		
			М	0.70 REF.		

Typical Circuit



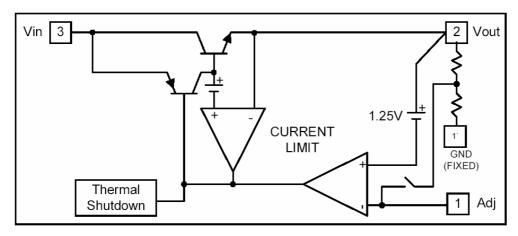


(5V/2.5V ADJ output)

Note:
$$V_o = V_{REF} * (1 + \frac{R_2}{R_1})$$

GM1117A Page: 1/4

Block Diagram



Pin Descriptions

Name	I/O	Pin#	Function
Adj (GND)		1	A resistor divider from this pin to the Vout pin and ground sets the output voltage (Ground only for fixed mode)
Vout	0	2	The output of the regulator. A minimum of 10uF capacitor must be connected from this pin to ground to insure stability.
Vin	I	3	The input pin of regulator. Typically a large storage capacitor is connected from this pin to ground to insure that the input voltage does not sag below the minimum dropout voltage during the load transient response. This pin must always be 1.3V higher than Vout in order for the device to regulate properly.

Absolute Maximum Ratings

Symbol	Parameter	Ratings	Unit
Vin	DC Supply Voltage	-0.3 to 12	V
PD	Power Dissipation	Internally Limited	
TST	Storage Temperature	-65 ~ + 150	:
TOP	Operating Junction Temperature Range	0 ~ + 150	:

GM1117A Page: 2/4

Electrical Characteristics

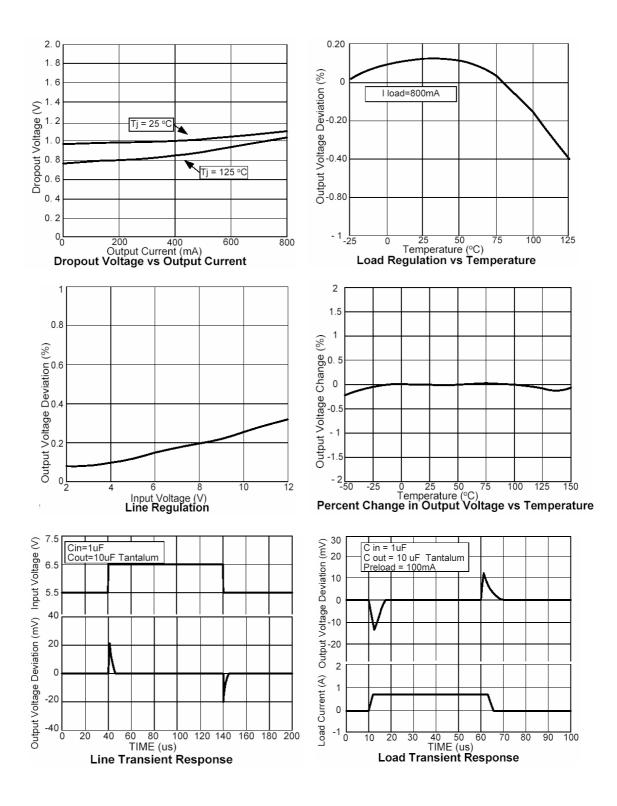
Parameter	r Conditions		MIN	TYP	MAX	UNIT
Reference Voltage	GM1117AADJ	Io=10mA, Tj=25:, (Vin-Vout)=1.5V		1.250	1.275	V
	GM1117A-1.5	Io=10mA, Tj=25 : , 3.0V≤Vin≤12V		1.500	1.530	V
	GM1117A-1.8	lo=10mA, Tj=25 : , 3.3V≤Vin≤12V		1.800	1.836	V
Output Voltage	GM1117A-2.5	lo=10mA, Tj=25 : , 4.0V≤Vin≤12V		2.500	2.550	V
	GM1117A-3.3	Io=10mA, Tj=25 : , 4.8V≤Vin≤12V		3.300	3.365	V
	GM1117A-5.0	Io=10mA, Tj=25 : , 6.5V≤Vin≤12V		5.000	5.100	V
Line Regulation	GM1117A-XXX	Io=10mA, Vout+1.5V <vin<12v, tj="25:</td"><td>-</td><td>0.2</td><td>%</td></vin<12v,>		-	0.2	%
	GM1117AADJ	Vin=3.3V, Vadj=0, 0mA <lo<1a, (note="" 1,2)<="" :="" td="" tj="25"><td>-</td><td>1</td><td>%</td></lo<1a,>		-	1	%
	GM1117A-1.5	Vin=3.0V, 0mA <lo<1a, (note="" 1,2)<="" td="" tj="25:"><td>12</td><td>15</td><td>mV</td></lo<1a,>		12	15	mV
Load Regulation	GM1117A-1.8	Vin=3.3V, 0mA <lo<1a, (note="" 1,2)<="" td="" tj="25:"><td>15</td><td>18</td><td>mV</td></lo<1a,>		15	18	mV
Load negulation	GM1117A-2.5	Vin=4.0V, 0mA <lo<1a, (note="" 1,2)<="" td="" tj="25:"><td>20</td><td>25</td><td>mV</td></lo<1a,>		20	25	mV
	GM1117A-3.3	Vin=5.0V, 0mA <lo<1a, (note="" 1,2)<="" td="" tj="25:"><td>26</td><td>33</td><td>mV</td></lo<1a,>		26	33	mV
	GM1117A-5.0	Vin=8.0V, 0mA <lo<1a, (note="" 1,2)<="" td="" tj="25:"><td>-</td><td>40</td><td>50</td><td>mV</td></lo<1a,>	-	40	50	mV
Dropout Voltage (VIN-VOUT)	GM1117A-XXX	Io=1A, (ΔVout=0.1% Vout)	-	1.3	1.4	V
Current Limit	GM1117A-XXX	Vin-Vout=5V	1.1	-	-	Α
Minimum Load Current	Adjustable model	Vin=5V	-	5	10	mA
Adjust Pin Current	Adjustable model	Vin=12V, Io=10mA	-	50	100	uA
Quiescent Current	fixed model	Vin=12V, Io=0mA	-	-	12	mA
Thermal Regulation	Regulation Ta=25: ,30ms pulse		-	0.008	0.04	%/W
Dinale Dejection	F=120HZ,Cout=25uF Tantalum, Iout=1A					
Ripple Rejection	GM1117A-XXX	VIN=VOUT+3V	-	60	70	dB
Temperature Stability Io=10mA		-	0.5	-	%	
θJA Thermal Resistance Junction-to-Ambient(No heat sink ;No air flow)			-	300	-	: /W
Our Thermal Resistance Junction-to-Case Control Circuitry/Power Transistor		-	100	-	: /W	

Note 1: See thermal regulation specifications for changes in output voltage due to heating effects. Line and load regulation are measured at a constant junction Temperature by low duty cycle pulse testing. Load regulation is measured at the output lead =1/18" from the package.

GM1117A Page: 3/4

Note 2: Line and load regulation are guaranteed up to the maximum power dissipation of 3W. Power dissipation is determined by the difference in input and output and the output current. Guaranteed maximum power dissipation will not be available over the full input/output range.

Characteristics Curve



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Head Office And Factory:

Talwan: No. 17-1 Tatung Rd. Fu Kou Hsin-Chu Industrial Park, Hsin-Chu, Taiwan, R. O. C.

TEL: 886-3-597-7061 FAX: 886-3-597-9220, 597-0785

China: (201203) No.255, Jang-Jiang Tsai-Lueng RD., Pu-Dung-Hsin District, Shang-Hai City, China
TEL: 86-21-5895-7671 ~ 4 FAX: 86-21-38950165

GM1117A Page: 4/4